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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/530,883	04/11/2005	Yoshitaka Sugawara	3688KE-1	9237
22442 SHERIDAN ROSS PC 1560 BROADWAY SUITE 1200 DENVER, CO 80202	7590 05/27/2008			
EXAMINER				
SEFER, AHMED N				
ART UNIT		PAPER NUMBER		
2826				
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Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Office Action Summary

Application No.

10/530,883

Applicant(s)

SUGAWARA, YOSHITAKA

Examiner

Ahmed Sefer

Art Unit

2826

Period for Reply -- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 27 March 2008.
- 2a) ☒ This action is **FINAL**. 2b) ☐ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1,5,7,8,10,11,18-22 and 26-30 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 1,5,7,8,10,11,18-22 and 26-30 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on _____ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.
- Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
- Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
 2. ☐ Certified copies of the priority documents have been received in Application No. _____.
 3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- 1) ☒ Notice of References Cited (PTO-892)
- 2) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)
- 3) ☒ Information Disclosure Statement(s) (PTO/SB/08)
Paper No(s)/Mail Date 2/12/08 & 3/27/08
- 4) ☐ Interview Summary (PTO-413)
Paper No(s)/Mail Date _____
- 5) ☐ Notice of Informal Patent Application
- 6) ☐ Other: _____

DETAILED ACTION

Response to Amendment

1. The amendment filed February 11, 2008 has been entered. Claims 2-4, 6, 9, 12-17 and 23-25 have been canceled.

Claim Rejections - 35 USC § 103

2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

3. The following is a quotation of 35 U.S.C. § 112, sixth paragraph, which forms the basis for determining interpreting certain forms of functional language in claims:

An element in a claim for a combination may be expressed as a means or step for performing a specified function without the recital of structure, material, or acts in support thereof, and such claim shall be construed to cover the corresponding structure, material, or acts described in the specification and equivalents thereof. 35 USC 112 paragraph 6.

4. According to MPEP 2181, limitations in amended claim 1 and newly submitted claim 18 will be presumed to invoke 35 U.S.C. 112, sixth paragraph, if the following 3-prong analysis is met:

- (A) the claim limitations must use the phrase "means for " or "step for,"
- (B) the "means for " or "step for " must be modified by functional language; and
- (C) the phrase "means for " or "step for " must not be modified by sufficient structure, material, or acts for achieving the specified function.

With respect to part A, the claim limitations in claims 1 and 18 use the phrase "means for."

With respect to part B, the claim limitations in claims 1 and 18 are modified by functional language calling for, “heating said wide-gap bipolar semiconductor element in said semiconductor package at a temperature of 125 °C or more.

With respect to part C, the claim limitations in claims 1 and 18 are not be modified by sufficient structure.

Therefore, claims 1, 18, and all other claims that depend from claim 1 are presumed to invoke 35 U.S.C. 112, sixth paragraph and the claim limitations shall be construed to cover the corresponding structure, material, or acts described in the specification and equivalents thereof. In the instant case, the limitation, “means for heating” will be construed to cover a heater having a nichrome wire and a heat sink (see pp. 27 and 51, lines 7-11 and 13-15 respectively).

5. Claims 1, 8, 11, 19, 20 and 26-29 are rejected under 35 U.S.C. 103(a) as being unpatentable over Sugawara JP-2002-325355 (“Sugawara ‘55”) (**of record**) in view of Sugawara, “Recent Progress in Sic Power Device Developments and Application Studies,” April 14-17. 2003, Cambridge, UK. pp. 10-18 (“Sugawara ‘03”).

Sugawara ‘55 discloses in figs. 1-4 a semiconductor device comprising: a wide-gap bipolar semiconductor element 24/26 using a wide-gap semiconductor and having a built-in voltage in the forward direction, a semiconductor package 1010 accommodating said wide-gap bipolar semiconductor element and having electrical connection means (106, 1289A, 1289B, 128) for connecting said wide-gap bipolar semiconductor element to external apparatuses, but does not specifically disclose heating means.

Sugawara '03 discloses (pp. 12 and 15, numeral III and V, B respectively) a semiconductor device comprising: a wide-gap bipolar semiconductor element and a compact heat sink.

Therefore, in view of Sugawara '03's teachings, one having an ordinary skill in the art at the time the invention was made would be motivated to modify Sugawara '55 by incorporating a heat sink. The motivation for doing so would have been to reduce the built-in potential and lower total power loss as taught by Sugawara (page 15, left col., first par.). Therefore, it would have been obvious to combine Sugawara '55 and Sugawara '03 to yield the device structure as recited in claim 1.

The applicant's claim 1 does not distinguish over the combined references regardless of the functions allegedly performed by the claimed device, because only the device per se is relevant, not the recited functions of stacking faults including basal plane dislocations. In this case it is reasonable to assume that cited device is capable of forming the stacking faults during operation of the device. See also col. 4, lines 1-28 of Sumakeris et al. (USPN 6,849,874) cited in the IDS filed 3/27/08. Because it is reasonable to assume that cited device is capable of performing the claimed function, the burden shifts to Applicants to show that it are not. See MPEP § 2114.

Furthermore, it is noted that functional language in a device claim is directed to the device per se, no matter which of the device's functions is referred to in the claim. *Hewlett-Packard Co. v. Bausch & Lomb Inc.*, 909 F.2d 1464, 1469, 15 USPQ2d 1525, 1528 (Fed. Cir. 1990) ("[A]pparatus claims cover what a device *is*, not what a device *does*" [emphasis in original]), makes it clear that it is the patentability of the device per se which must be determined in a "functional language" claim and not the patentability of the function, and that an old or obvious

device alleged to perform a new function is not patentable as a device, whether claimed in “functional language” terms or not. Note that case law makes clear that in such cases applicant has the burden of showing that a prior art device that appears reasonably capable of performing the allegedly novel function is in fact incapable of doing so. See *In re King*, 231 USPQ 136 (Fed. Cir, 1986) (“It did not suffice merely to assert that the cited does not inherently achieve the claimed function, challenging the PTO to prove the contrary by experiment or otherwise. The PTO is not equipped to perform such tasks”) and *In re Best*, 562 F.2d 1252, 1254, 195 USPQ 430, 433 (CCPA 1977) (claiming a new use, new function or unknown property which is inherently present in the prior art does not necessarily make the claim patentable). See MPEP § 2114.

Re claim 8, Sugawara '03 discloses (pp. 12 and 15, numeral III and V, B respectively) a heat sink that raises the temperature of said wide-gap bipolar semiconductor element. Sugawara '03' teaches a compact heat sink which is understandably capable of receiving and dissipating heat; thus the limitation, “by controlling a radiation of heat generated when said wide-gap bipolar semiconductor element is energized” is met.

Re claim 11, Sugawara '55 discloses (see paragraph [41] of machine translated document) the wide-gap bipolar semiconductor element 24/26 being a gate drive type SiC-GTO thyristor. Thus, the limitation, “the wide-gap semiconductor being a self-excited thyristor” is met.

Re claim 19, Sugawara '55 discloses a support made of metal 9, on which the wide-gap bipolar semiconductor element is mounted.

Re claim 20, Sugawara '55 discloses a cap 4 made of metal fixed on the support so as to cover the wide-gap bipolar semiconductor element.

Re claims 26-29, the recited limitations do not further limit the device structure, but only limit its method of heating.

6. Claims 1, 5, 7, 10, 11, 19, 20 and 26-29 are rejected under 35 U.S.C. 103(a) as being unpatentable over "Sugawara '55" in view of Tato ("Tato") JP 9-148681 (of record).

Sugawara '55 discloses in figs. 1-4 a semiconductor device comprising: a wide-gap bipolar semiconductor element 24/26 using a wide-gap semiconductor and having a built-in voltage in the forward direction, a semiconductor package 1010 accommodating said wide-gap bipolar semiconductor element and having electrical connection means (106, 1289A, 1289B, 128) for connecting said wide-gap bipolar semiconductor element to external apparatuses, but does not specifically disclose heating means.

Tato discloses in figs. 1 and 2 a semiconductor device comprising: a wide-gap semiconductor element and a heater.

Therefore, in view of Tato's teachings, one having an ordinary skill in the art at the time the invention was made would be motivated to modify Sugawara '55 by incorporating a heater. The motivation for doing so would have been to raise the temperature of the device as taught by Tato. Therefore, it would have been obvious to combine Sugawara '55 and Tato to yield the device structure as recited in claim 1.

The applicant's claim 1 does not distinguish over the combined references regardless of the functions allegedly performed by the claimed device, because only the device per se is relevant, not the recited functions of stacking faults including basal plane dislocations. In this case it is

reasonable to assume that cited device is capable of forming the stacking faults during operation of the device. See also col. 4, lines 1-28 of Sumakeris et al. (USPN 6,849,874) cited in the IDS filed 3/27/08. Because it is reasonable to assume that cited device is capable of performing the claimed function, the burden shifts to Applicants to show that it are not. See MPEP § 2114.

Furthermore, it is noted that functional language in a device claim is directed to the device per se, no matter which of the device's functions is referred to in the claim. *Hewlett-Packard Co. v. Bausch & Lomb Inc.*, 909 F.2d 1464, 1469, 15 USPQ2d 1525, 1528 (Fed. Cir. 1990) ("[A]pparatus claims cover what a device *is*, not what a device *does*" [emphasis in original]), makes it clear that it is the patentability of the device per se which must be determined in a "functional language" claim and not the patentability of the function, and that an old or obvious device alleged to perform a new function is not patentable as a device, whether claimed in "functional language" terms or not. Note that case law makes clear that in such cases applicant has the burden of showing that a prior art device that appears reasonably capable of performing the allegedly novel function is in fact incapable of doing so. See *In re King*, 231 USPQ 136 (Fed. Cir, 1986) ("It did not suffice merely to assert that the cited does not inherently achieve the claimed function, challenging the PTO to prove the contrary by experiment or otherwise. The PTO is not equipped to perform such tasks") and *In re Best*, 562 F.2d 1252, 1254, 195 USPQ 430, 433 (CCPA 1977) (claiming a new use, new function or unknown property which is inherently present in the prior art does not necessarily make the claim patentable). See MPEP § 2114.

Re claim 5, Tao discloses said heating means heats the semiconductor element. Tato also discloses (see abstract) that the heater is not used at the time of high temperature operation of the

semiconductor element; thus, the recitation calling for, “in advance before the start of the operation of said wide-gap bipolar semiconductor element” is met.

Re claim 7, Tato discloses (see paragraph [0006] of machine translated document) the heater includes a NiCr (similar to applicants discloses heater including nichrome); thus, the recitation calling for, “said heating means is an electric heater providing heat to said wid-gap bipolar semiconductor element” is met.

Re claim 10, Tato discloses (see abstract) a temperature sensor 10 to monitor the temperature of the semiconductor element and a temperature control circuit (not shown); thus, the recitation calling for, “wherein said semiconductor package has a temperature sensor for detecting the temperature of said wide-gap bipolar semiconductor element and a temperature controller that keeps the temperature of said wide-gap bipolar semiconductor element at a temperature of 125 °C or more on the basis of a detection output of said temperature sensor” is met.

Re claim 11, Sugawara '55 discloses (see paragraph [41] of machine translated document) the wide-gap bipolar semiconductor element 24/26 being a gate drive type SiC-GTO thyristor. Thus, the limitation, “the wide-gap semiconductor being a self-excited thyristor” is met.

Re claim 19, Sugawara '55 discloses a support made of metal 9, on which the wide-gap bipolar semiconductor element is mounted.

Re claim 20, Sugawara '55 discloses a cap 4 made of metal fixed on the support so as to cover the wide-gap bipolar semiconductor element.

Re claims 26-29, the recited limitations do not further limit the device structure, but only limit its method of heating.

7. Claims 21 and 30 rejected under 35 U.S.C. 103(a) as being unpatentable over Sugawara '55 in view of Tato as applied to claims 1 and 19 above, and further in view of Nakajima et al. ("Nakajima") US PG-Pub 2003/0213979.

The combined references disclose the device structure as recited in the claim including a bipolar element being bonded to a upper face of as support 103, but do not specifically disclose means for heating being located on the lower face of the support.

Nakajima discloses a bipolar element 1 being bonded to an upper face of as support 15, and a means for heating 16 being located on a lower face of the support.

Therefore, in view of Nakajima's teachings, one having an ordinary skill in the art at the time the invention was made would be motivated to incorporate a heating means located on the lower face of the support so as to provide a proper means for heating.

Re claim 30, Nakajima discloses a package comprising a molded heat-resistant 14 encapsulating the bipolar element.

8. Claim 18 is rejected under 35 U.S.C. 103(a) as being unpatentable over "Sugawara '55" in view of Tato.

Sugawara '55 discloses in figs. 1-4 a semiconductor device comprising: a wide-gap bipolar semiconductor element 24/26 using a wide-gap semiconductor and having a built-in voltage in the forward direction, a semiconductor package 1010 accommodating said wide-gap bipolar semiconductor element and having electrical connection means (106, 1289A, 1289B,

128) for connecting said wide-gap bipolar semiconductor element to external apparatuses, but discloses neither heating means nor temperature sensor nor controller.

Tato discloses (figs. 1 and 2 and abstract) a semiconductor device comprising: a wide-gap semiconductor element and a heater (heating means); a temperature sensor 10; and a temperature control circuit (not shown).

Therefore, in view of Tato's teachings, one having an ordinary skill in the art at the time the invention was made would be motivated to modify Sugawara '55 by incorporating a heater, a temperature sensor; and a temperature controller. The motivation for doing so would have been to raise, monitor and adjust the temperature of the device, as taught by Tato. Therefore, it would have been obvious to combine Sugawara '55 and Tato to yield the device structure as recited in claim 18.

The applicant's claim 18 does not distinguish over the combined references regardless of the functions allegedly performed by the claimed device, because only the device per se is relevant, not the recited functions of stacking faults including basal plane dislocations. In this case it is reasonable to assume that cited device is capable of forming the stacking faults during operation of the device. See also col. 4, lines 1-28 of Sumakeris et al. (USPN 6,849,874) cited in the IDS filed 3/27/08. Because it is reasonable to assume that cited device is capable of performing the claimed function, the burden shifts to Applicants to show that it are not. See MPEP § 2114.

Furthermore, it is noted that functional language in a device claim is directed to the device per se, no matter which of the device's functions is referred to in the claim. *Hewlett-Packard Co. v. Bausch & Lomb Inc.*, 909 F.2d 1464, 1469, 15 USPQ2d 1525, 1528 (Fed. Cir. 1990) ("[A]pparatus claims cover what a device *is*, not what a device *does*" [emphasis in original]),

makes it clear that it is the patentability of the device per se which must be determined in a "functional language" claim and not the patentability of the function, and that an old or obvious device alleged to perform a new function is not patentable as a device, whether claimed in "functional language" terms or not. Note that case law makes clear that in such cases applicant has the burden of showing that a prior art device that appears reasonably capable of performing the allegedly novel function is in fact incapable of doing so. See *In re King*, 231 USPQ 136 (Fed. Cir, 1986) ("It did not suffice merely to assert that the cited does not inherently achieve the claimed function, challenging the PTO to prove the contrary by experiment or otherwise. The PTO is not equipped to perform such tasks") and *In re Best*, 562 F.2d 1252, 1254, 195 USPQ 430, 433 (CCPA 1977) (claiming a new use, new function or unknown property which is inherently present in the prior art does not necessarily make the claim patentable). See MPEP § 2114.

Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37

CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to A. Sefer whose telephone number is (571) 272-1921.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Sue Purvis can be reached on (571) 272-1236.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

/A. Sefer/
Primary Examiner
Art Unit 2826